NSN 5961-01-193-5719

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-193-5719 **Inclosure Material:** Plastic **Overall Length:** 1.230 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220b **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.0 emitter to base voltage, static, collector open and 350.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No